



100V N-Channel Enhancement Mode MOSFET

Voltage

100 V

Current

2.7 A

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@2.7A<152m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@2.5A<158m\Omega$
- Advanced Trench Process Technology
- High density cell design for ultra low on-resistance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

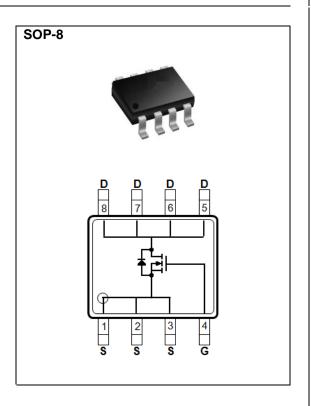
Mechanical Data

• Case: SOP-8 package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0029 ounces, 0.083 grams

Marking: L9454A



$\textbf{Maximum Ratings and Thermal Characteristics} \; (T_A \!\!=\!\! 25^{\circ}\! \text{C unless otherwise noted})$

PARAME	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V _{DS}	100	V	
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _A =25°C		2.7		
	T _A =70°C	I _D	2.1	Α	
Pulsed Drain Current (Note 1)		I _{DM}	10.8	А	
Power Dissipation	T _A =25°C		2.5	107	
	T _A =70°C	P _D	1.6	W	
Single Pulse Avalanche Energy (Note 5)		E _{AS}	1.3	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal resistance - Junction to Ambient, $t \le 10s^{\text{(Note 6)}}$		R _{θJA}	50	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V,I _D =250uA	100	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	1.0	1.72	2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =2.7A	-	130	152	mΩ	
		V _{GS} =4.5V,I _D =2.5A	-	135	158		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =80V,V _{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 7)							
Total Gate Charge	Q_g	V _{DS} =60V, I _D =2.7A, V _{GS} =10V (Note 2,3)	-	19	-	nC	
Gate-Source Charge	Q_gs		-	2.9	-		
Gate-Drain Charge	Q_gd		-	3.2	-		
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	1021	-	pF	
Output Capacitance	Coss		-	38	-		
Reverse Transfer Capacitance	Crss		-	17	-		
Turn-On Delay Time	td _(on)	V 50V DI 1050	-	6.1	-	ns	
Turn-On Rise Time	tr	V_{DS} =50V,RL=18.5 Ω , V_{GS} =10V, R _G =6 Ω (Note 2,3)	-	27	-		
Turn-Off Delay Time	td _(off)		-	28	-		
Turn-Off Fall Time	tf		-	11	-		
Drain-Source Diode							
Maximum Continuous Drain-Source			-	-	2.7	А	
Diode Forward Current	I _S						
Diode Forward Voltage	V_{SD}	I _S =1.0A, V _{GS} =0V	-	0.74	1.2	V	

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. The test condition is L=0.1mH, I_{AS} =5A, V_{DD} =50V, V_{GS} =10V
- 6. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 7. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

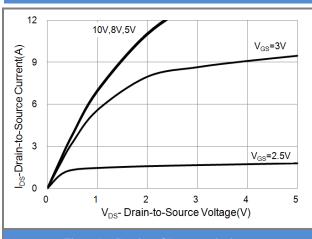


Fig.1 On-Region Characteristics

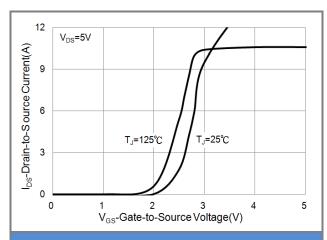


Fig.2 Transfer Characteristics

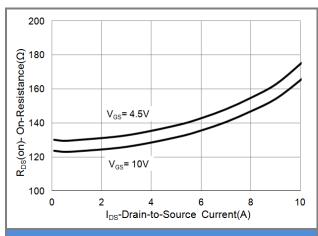


Fig.3 On-Resistance vs. Drain Current

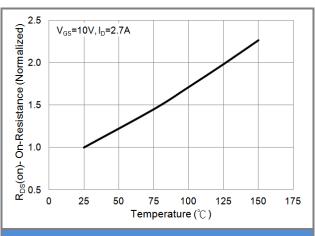
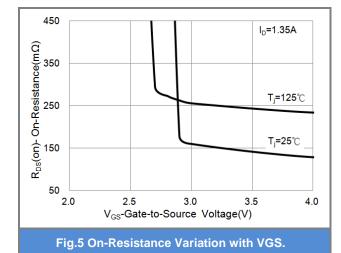
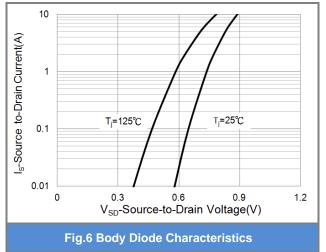


Fig.4 On-Resistance vs. Junction temperature









TYPICAL CHARACTERISTIC CURVES

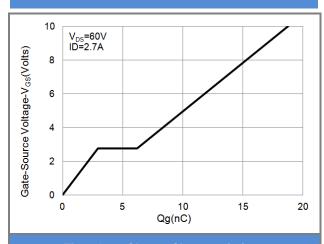


Fig.7 Gate-Charge Characteristics

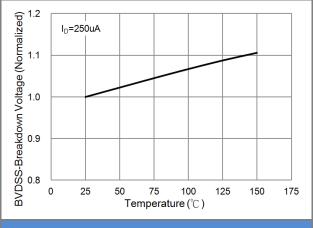


Fig.8 Breakdown Voltage Variation vs. Temperature

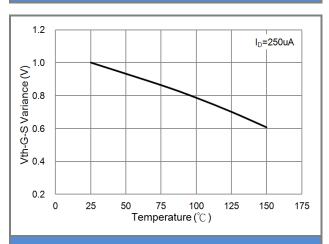


Fig.9 Threshold Voltage Variation with Temperature.

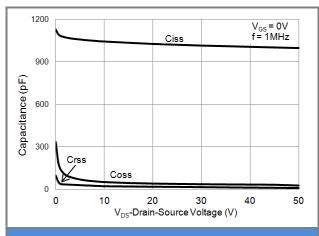


Fig.10 Capacitance vs. Drain-Source Voltage.

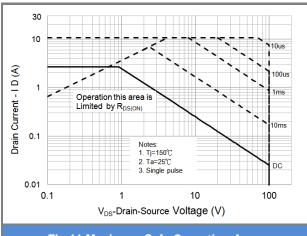


Fig.11 Maximum Safe Operating Area





TYPICAL CHARACTERISTIC CURVES

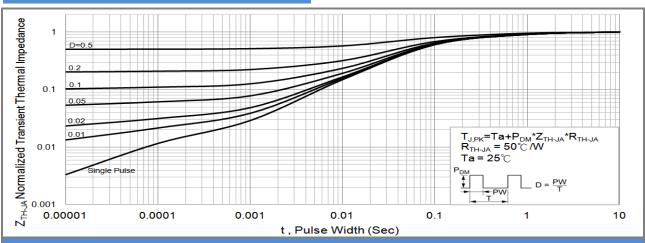


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

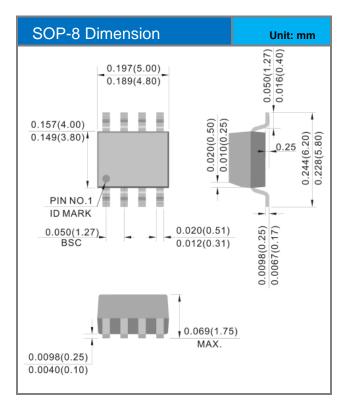


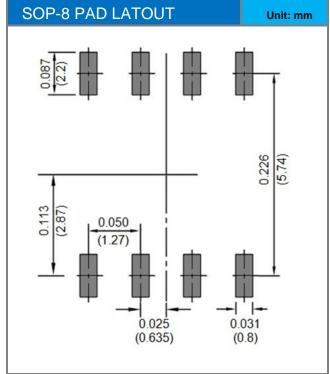


PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJL9450A_R2_00001	SOP-8	2.5K pcs / 13" reel	L9450A	Halogen free

Packaging Information & Mounting Pad Layout









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